

# 0.8 V to 2.5 V, 28 mΩ, Slew Rate Controlled Load Switch in WCSP4

## DESCRIPTION

The SiP32454 and SiP32455 are slew rate controlled integrated high side load switches that operate in the input voltage range from 0.8 V to 2.5 V. The SiP32454 and SiP32455 are of n-channel MOSFET switching elements that provide 28 mΩ switch on resistance. They have a 1 ms at 1.2 V and 1.5 ms at 2.5 V slow slew rate that limits the in-rush current and minimizes the switching noise. These devices' low voltage logic control threshold can interface with low voltage control I/O directly without extra level shift or driver. A 2 MW pull-down resistor is integrated at logic control EN pin. SiP32454 integrates a switch off output discharge circuit.

Both SiP32454 and SiP32455 are available in compact wafer level CSP package, WCSP4 0.8 mm x 0.8 mm with 0.4 mm pitch.

## FEATURES

- Low input voltage, 0.8 V to 2.5 V
- Low  $R_{ON}$ , 28 mΩ typical
- Slew rate control
- Low logic control with hysteresis
- Reverse current blocking when disabled
- Integrated output discharge switch for SiP32454
- Integrated pull down resistor at EN pin
- 4 bump WCSP 0.8 mm x 0.8 mm with 0.4 mm pitch package
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



## APPLICATIONS

- Battery operated devices
- Smart phones
- GPS and PMP
- Computer
- Medical and healthcare equipment
- Industrial and instrument
- Cellular phones and portable media players
- Game consol

## TYPICAL APPLICATION CIRCUIT

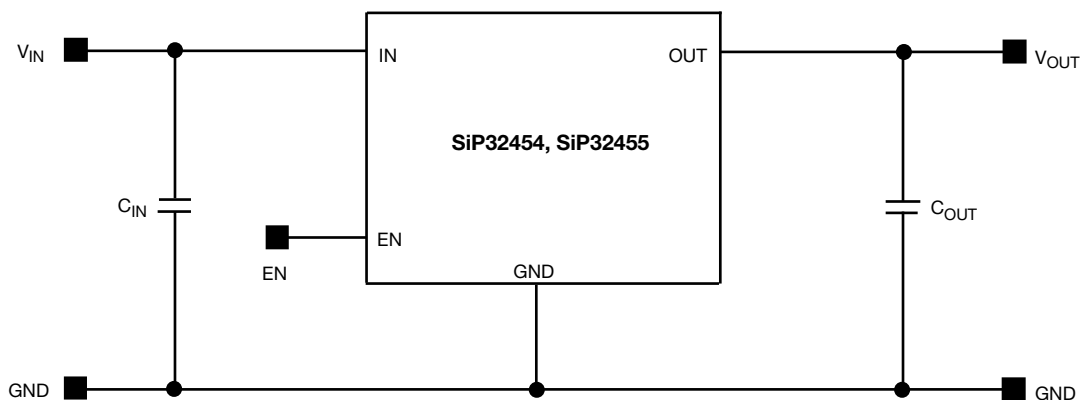


Fig. 1 - SiP32454 and SiP32455 Typical Application Circuit

| ORDERING INFORMATION |   |         |                   |
|----------------------|---|---------|-------------------|
| TEMPERATURE RANGE    | PACKAGE   | MARKING | PART NUMBER       |
| -40 °C to +85 °C     | WCSP: 4 bumps (2 x 2, 0.4 mm pitch, 208 μm bump height, 0.8 mm x 0.8 mm die size) | AD      | SiP32454DB-T2-GE1 |
|                      |   | AE      | SiP32455DB-T2-GE1 |

### Note

- -GE1 denotes halogen-free and RoHS-compliant



| ABSOLUTE MAXIMUM RATINGS  |              |      |
|---|--------------|------|
| PARAMETER   | LIMIT        | UNIT |
| Supply input voltage ( $V_{IN}$ )   | -0.3 to 2.75 | V    |
| Enable input voltage ( $V_{EN}$ )   | -0.3 to 2.75 |      |
| Output voltage ( $V_{OUT}$ )  | -0.3 to 2.75 |      |
| Maximum continuous switch current ( $I_{max.}$ )  | 1.2          | A    |
| Maximum repetitive pulsed current ( $I_{DM}$ ) $V_{IN}$ (pulsed at 1 ms, 10 % duty cycle) | 2            |      |
| ESD rating (HBM)  | 4000         | V    |
| Junction temperature ( $T_J$ )  | -40 to +150  | °C   |
| Thermal resistance ( $\theta_{JA}$ ) <sup>a</sup>   | 280          | °C/W |
| Power dissipation ( $P_D$ ) <sup>a</sup>  | 196          | mW   |

**Notes**

- a. Device mounted with all leads and power pad soldered or welded to PC board, see PCB layout  
b. Derate 3.6 mW/°C above  $T_A = 25$  °C

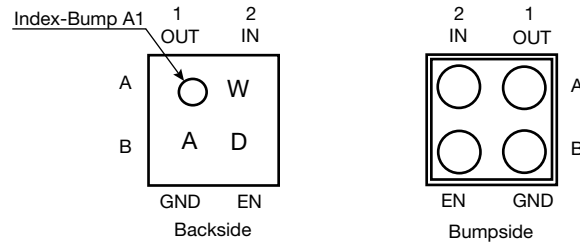
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

| RECOMMENDED OPERATING RANGE                    |             |      |
|--|-------------|------|
| PARAMETER                                      | LIMIT       | UNIT |
| Input voltage range ( $V_{IN}$ )               | 0.8 to 2.5  | V    |
| Operating junction temperature range ( $T_J$ ) | -40 to +125 | °C   |

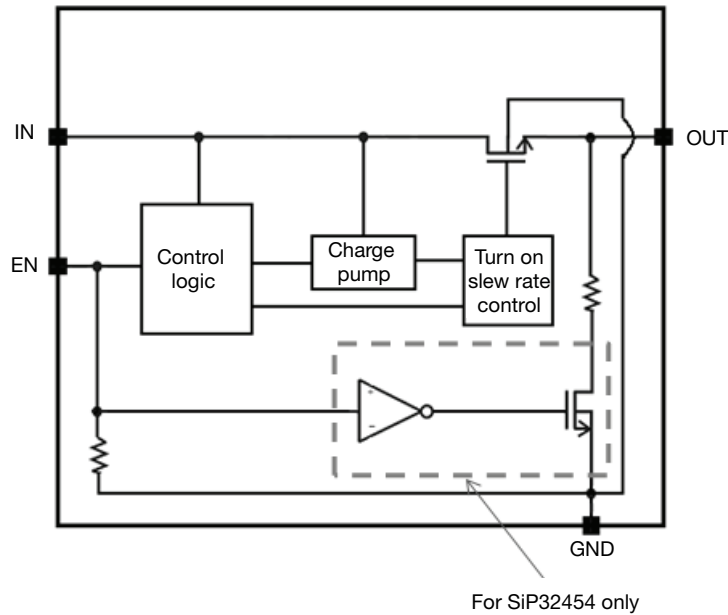
| SPECIFICATIONS                     |               |   |                   |                   |                   |        |
|------------------------------------|---------------|---|-------------------|-------------------|-------------------|--------|
| PARAMETER                          | SYMBOL        | TEST CONDITIONS UNLESS SPECIFIED<br>$V_{IN} = 1$ V, $T_A = -40$ °C to +85 °C<br>(typical values are at $T_A = 25$ °C) | LIMITS            |                   |                   | UNIT   |
|                                    |               |   | MIN. <sup>a</sup> | TYP. <sup>b</sup> | MAX. <sup>a</sup> |        |
| Operating voltage <sup>c</sup>     | $V_{IN}$      |   | 0.8               | -                 | 2.5               | V      |
| Quiescent current                  | $I_Q$         | $V_{IN} = 1.2$ V, $V_{EN} = V_{IN}$ , OUT = open  | -                 | 10                | 15                | μA     |
|                                    |               | $V_{IN} = 2.5$ V, $V_{EN} = V_{IN}$ , OUT = open  | -                 | 34                | 60                |        |
| Off supply current                 | $I_{Q(off)}$  | SiP32454  | -                 | -                 | 30                | μA     |
|                                    |               | SiP32455  | -                 | -                 | 1                 |        |
| Off switch current                 | $I_{DS(off)}$ | EN = GND, OUT = 0 V   | -                 | -                 | 30                |        |
| Reverse blocking current           | $I_{RB}$      | $V_{OUT} = 2.5$ V, $V_{IN} = 0.9$ V, $V_{EN} = 0$ V   | -                 | 0.001             | 30                |        |
| On-resistance                      | $R_{DS(on)}$  | $V_{IN} = 1$ V, $I_L = 200$ mA, $T_A = 25$ °C   | -                 | 30                | 35                | mΩ     |
|                                    |               | $V_{IN} = 1.2$ V, $I_L = 200$ mA, $T_A = 25$ °C   | -                 | 29                | 35                |        |
|                                    |               | $V_{IN} = 1.8$ V, $I_L = 200$ mA, $T_A = 25$ °C   | -                 | 28                | 35                |        |
|                                    |               | $V_{IN} = 2.5$ V, $I_L = 200$ mA, $T_A = 25$ °C   | -                 | 28                | 35                |        |
| On-resistance temp. coefficient    | $TC_{RDS}$    |   | -                 | 4100              | -                 | ppm/°C |
| Output pull-down resistance        | $R_{PD}$      | $V_{EN} = 0$ V, $T_A = 25$ °C (SiP32454 only)   | -                 | 417               | 550               | Ω      |
| EN input low voltage <sup>c</sup>  | $V_{IL}$      | $V_{IN} = 1$ V  | -                 | -                 | 0.1               | V      |
| EN input high voltage <sup>c</sup> | $V_{IH}$      | $V_{IN} = 2.5$ V  | 1.5               | -                 | -                 | V      |
| EN input leakage                   | $I_{EN}$      | $V_{IN} = 2.5$ V, $V_{EN} = 0$ V  | -                 | -                 | 1                 | μA     |
|                                    |               | $V_{IN} = 2.5$ V, $V_{EN} = 2.5$ V  | -                 | 6.5               | 12                |        |
| Output turn-on delay time          | $t_{d(on)}$   | $V_{IN} = 1.2$ V  | -                 | 0.6               | 1.2               | ms     |
|                                    |               | $V_{IN} = 2.5$ V  | -                 | 0.6               | 1.2               |        |
| Output turn-on rise time           | $t_r$         | $V_{IN} = 1.2$ V  | 0.4               | 1                 | 1.6               | ms     |
|                                    |               | $V_{IN} = 2.5$ V  | 0.5               | 1.5               | 2.5               |        |
| Output turn-off delay time         | $t_{d(off)}$  | $V_{IN} = 1.2$ V  | -                 | 0.3               | 1                 | μs     |
|                                    |               | $V_{IN} = 2.5$ V  | -                 | 0.1               | 1                 |        |

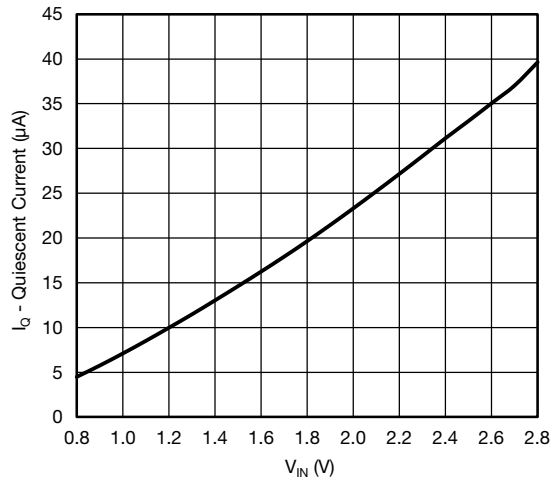
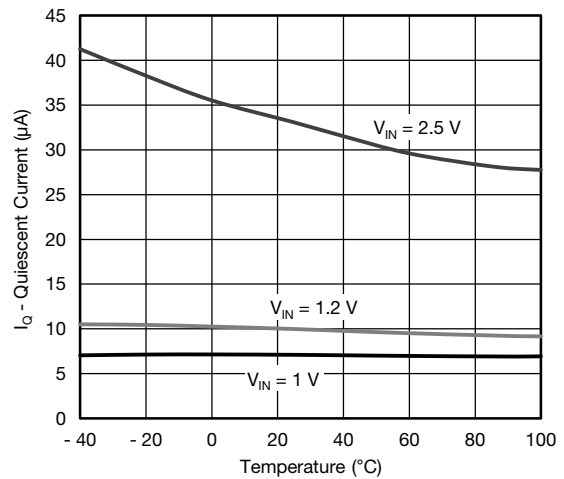
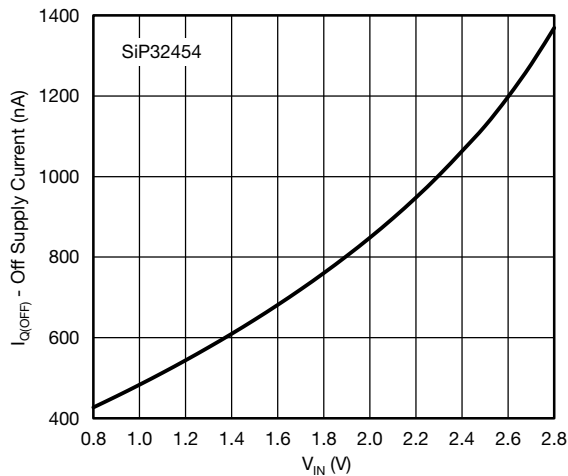
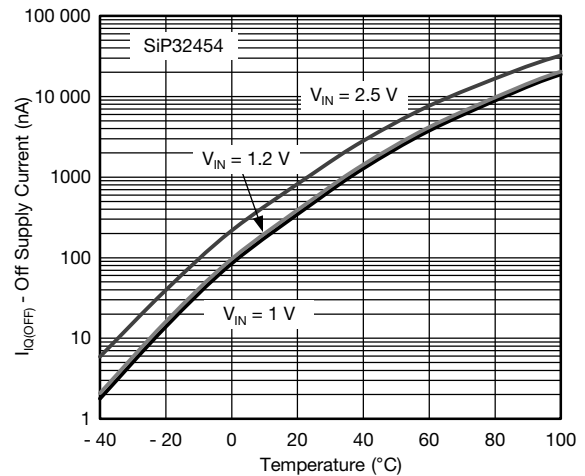
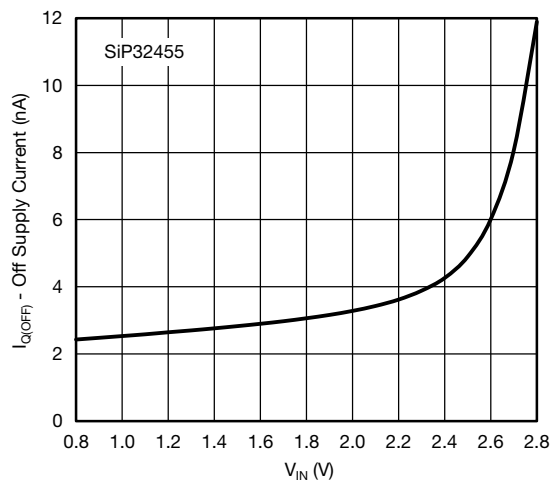
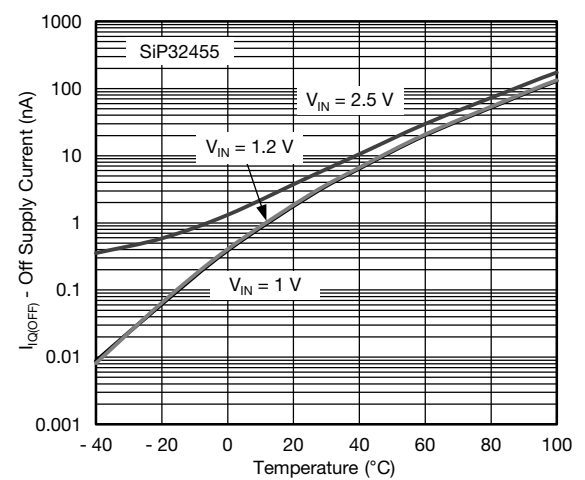
**Notes**

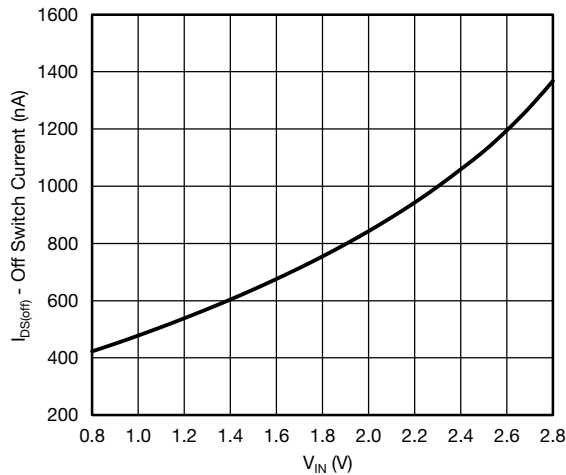
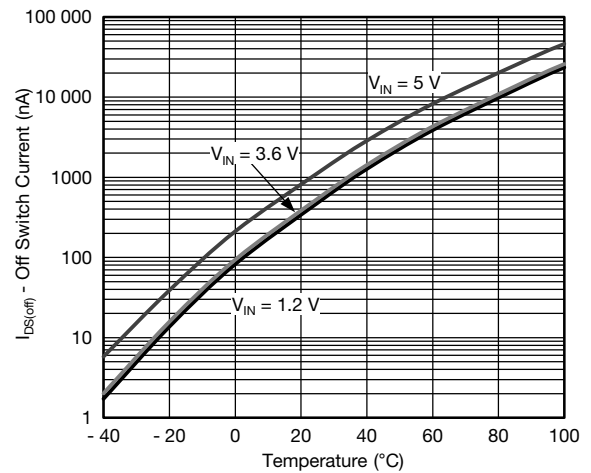
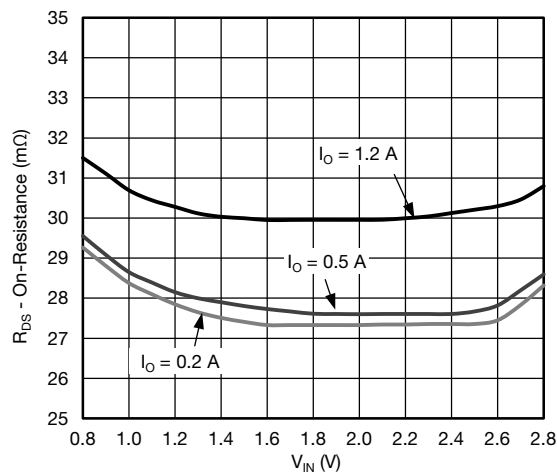
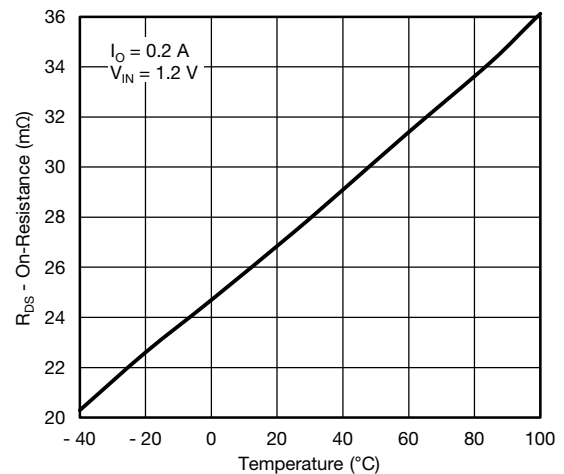
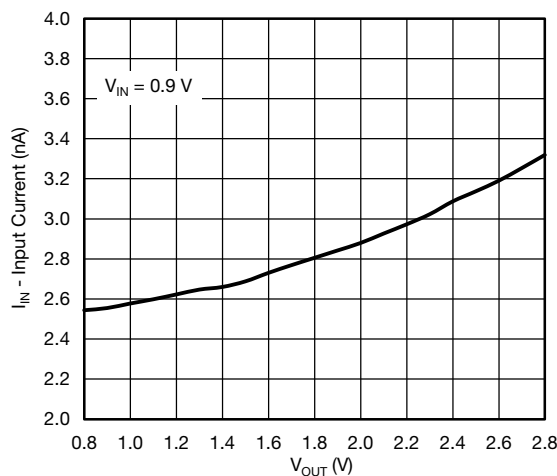
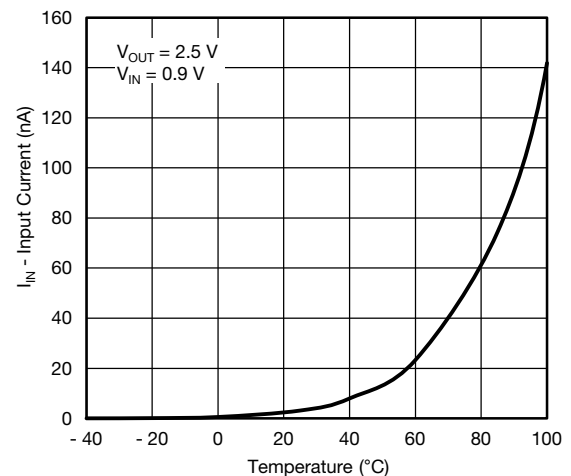
- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum  
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing  
c. For  $V_{IN}$  outside this range consult typical EN threshold curve

**PIN CONFIGURATION**

**Fig. 2 - WCSP 2 x 2 Package**

| PIN DESCRIPTION |      |                                      |
|-----------------|------|--------------------------------------|
| PIN NUMBER      | NAME | FUNCTION                             |
| A1              | OUT  | This is the output pin of the switch |
| A2              | IN   | This is the input pin of the switch  |
| B1              | GND  | Ground connection                    |
| B2              | EN   | Enable input                         |

**BLOCK DIAGRAM**

**Fig. 3 - Functional Block Diagram**

**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

**Fig. 4 - Quiescent vs. Input Voltage**

**Fig. 7 - Quiescent vs. Temperature**

**Fig. 5 - Off Supply Current vs. Input Voltage**

**Fig. 8 - Off Supply Current vs. Temperature**

**Fig. 6 - Off Supply Current vs. Input Voltage**

**Fig. 9 - Off Supply Current vs. Temperature**

**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

**Fig. 10 - Off Switch Current vs. Input Voltage**

**Fig. 13 - Off Switch Current vs. Temperature**

**Fig. 11 - On Resistance vs. Input Voltage**

**Fig. 14 - On Resistance vs. Temperature**

**Fig. 12 - Reverse Blocking Current vs. Output Voltage**

**Fig. 15 - Reverse Blocking Current vs. Temperature**

**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

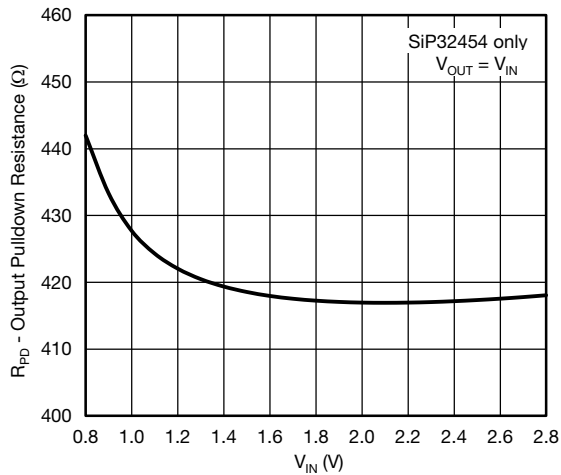


Fig. 16 - Output Pull-Down Resistance vs. Input Voltage

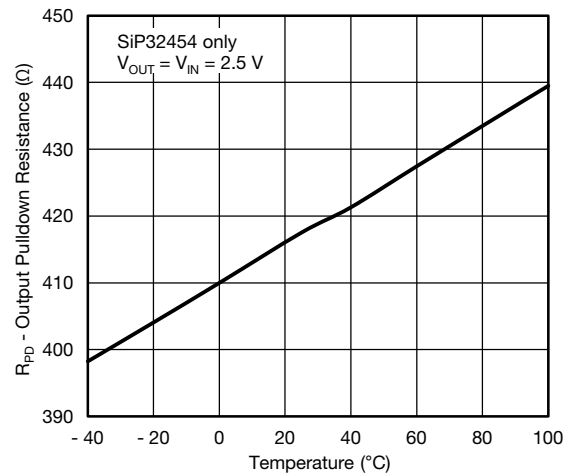


Fig. 19 - Output Pull-Down Resistance vs. Temperature

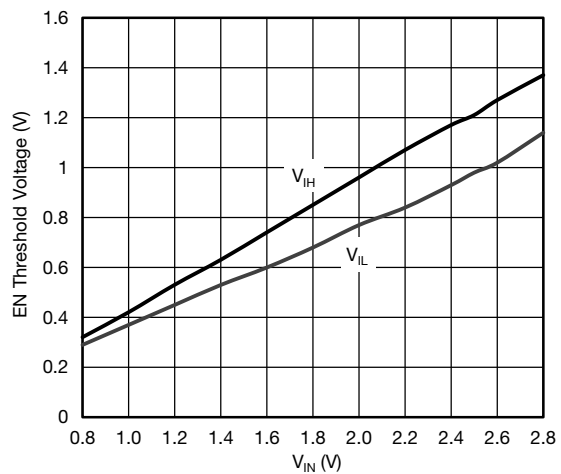


Fig. 17 - EN Threshold Voltage vs. Input Voltage

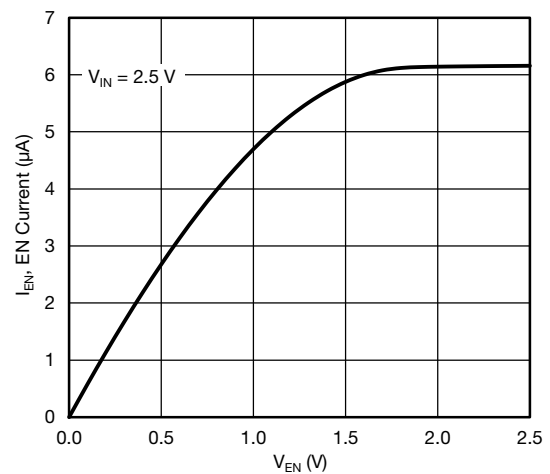


Fig. 20 - EN Input Leakage vs. V<sub>EN</sub>

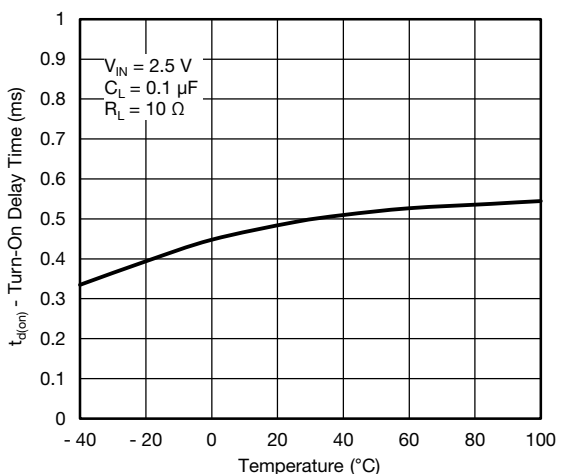


Fig. 18 - Turn-On Delay Time vs. Temperature

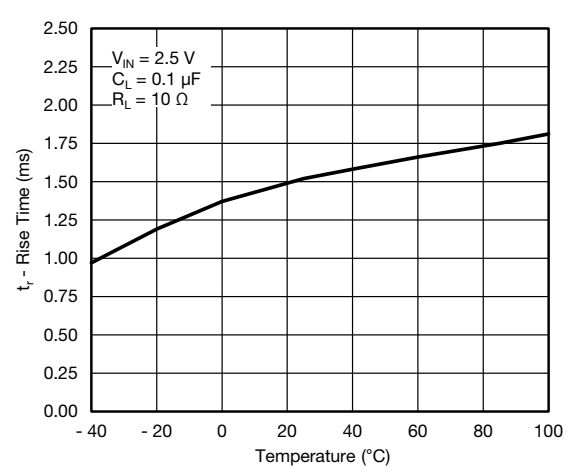


Fig. 21 - Rise Time vs. Temperature

**ELECTRICAL CHARACTERISTICS**

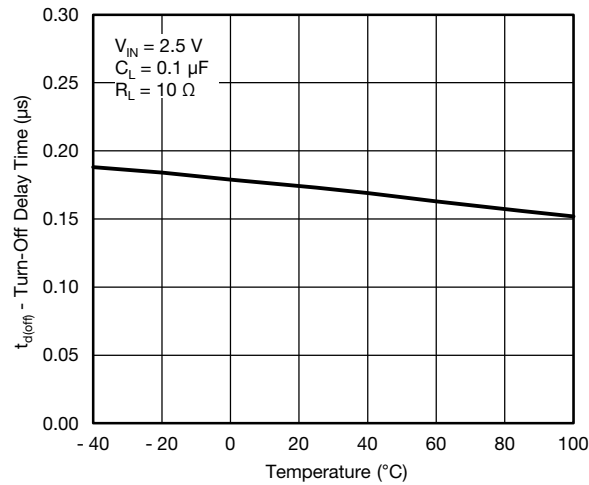


Fig. 22 - Turn-Off Delay Time vs. Temperature

**TYPICAL WAVEFORMS**

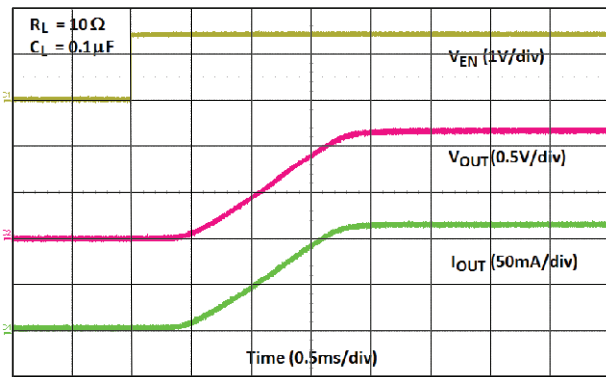


Fig. 23 - Turn-On Time ( $V_{IN} = 1.2 V$ )

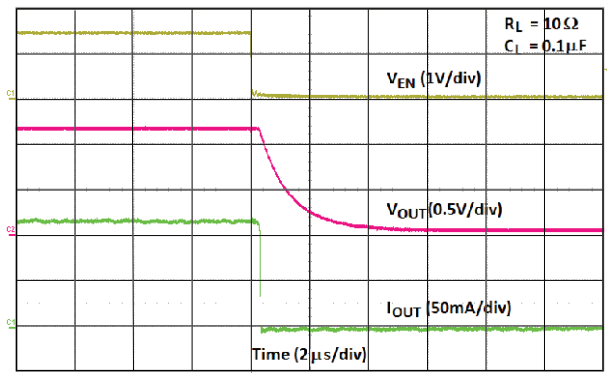


Fig. 25 - Turn-Off Time ( $V_{IN} = 1.2 V$ )

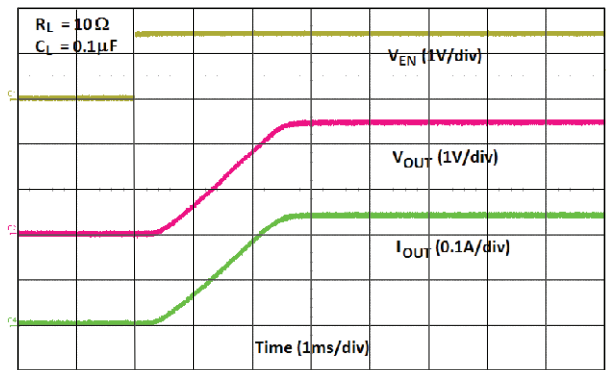


Fig. 24 - Turn-On Time ( $V_{IN} = 2.5 V$ )

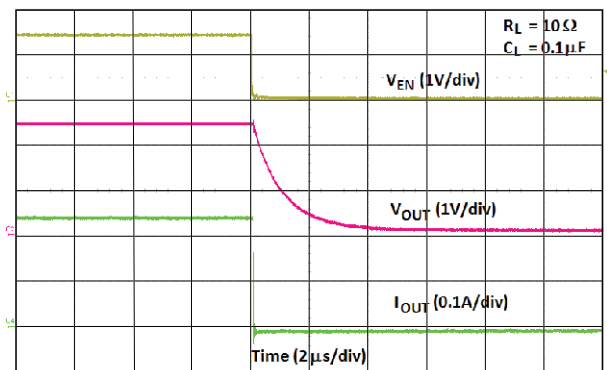


Fig. 26 - Turn-Off Time ( $V_{IN} = 2.5 V$ )



**DETAILED DESCRIPTION**

SiP32454 and SiP32455 are n-channel power MOSFET designed as high side load switch. Once enable the device charge pumps the gate of the power MOSFET to a constant gate to source voltage for fast turn on time. The mostly constant gate to source voltage keeps the on resistance low through out the input voltage range. SiP32454 and SiP32455 are designed with slow slew rate to minimize the inrush current during turn on. Because the body of the output n-channel is always connected to GND, it prevents the current from going back to the input in case the output voltage is higher than the output. The SiP32454 especially incorporates an active output pull-down resistor to discharge output capacitance when the device is off.

**APPLICATION INFORMATION**

**Input Capacitor**

While a bypass capacitor on the input is not required, a 4.7 μF or larger capacitor for C<sub>IN</sub> is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the input pin to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

**Output Capacitor**

A 0.1 μF capacitor across V<sub>OUT</sub> and GND is recommended to insure proper slew operation. There is inrush current through the output MOSFET and the magnitude of the inrush current depends on the output capacitor, the bigger the C<sub>OUT</sub> the higher the inrush current. There are no ESR or capacitor type requirement.

**Enable**

The EN pin is compatible with CMOS logic voltage levels. It requires at least 0.1 V or below to fully shut down the device and 1.5 V or above to fully turn on the device.

**Protection Against Reverse Voltage Condition**

Both the SiP32454 and SiP32455 can block the output current from going to the input in case where the output voltage is higher than the input voltage when the main switch is off.

**Thermal Considerations**

These devices are designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.2 A as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 280 °C/W) the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature, T<sub>J(max.)</sub> = 125 °C, the junction-to-ambient thermal resistance, θ<sub>JA</sub> = 280 °C/W, and the ambient temperature, T<sub>A</sub>, which may be formulaically expressed as:

$$P \text{ (max.)} = \frac{T_{J(max.)} - T_A}{\theta_{JA}} = \frac{125 - T_A}{280}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 196 mW.

So long as the load current is below the 1.2 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the R<sub>DS(on)</sub> at the ambient temperature.

As an example let us calculate the worst case maximum load current at T<sub>A</sub> = 70 °C. The worst case R<sub>DS(on)</sub> at 25 °C is 35 mΩ. The R<sub>DS(on)</sub> at 70 °C can be extrapolated from this data using the following formula:

$$R_{DS(on)} \text{ (at 70 °C)} = R_{DS(on)} \text{ (at 25 °C)} \times (1 + T_C \times \Delta T)$$

Where T<sub>C</sub> is 4100 ppm/°C. Continuing with the calculation we have

$$R_{DS(on)} \text{ (at 70 °C)} = 35 \text{ m}\Omega \times (1 + 0.0041 \times (70 \text{ °C} - 25 \text{ °C})) = 42.2 \text{ m}\Omega$$

The maximum current limit is then determined by

$$I_{LOAD(max.)} < \sqrt{\frac{P \text{ (max.)}}{R_{DS(on)}}}$$

which in this case is 2.1 A. Under the stated input voltage condition, if the 2.1 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 1.2 A only as listed in the Absolute Maximum Ratings table.



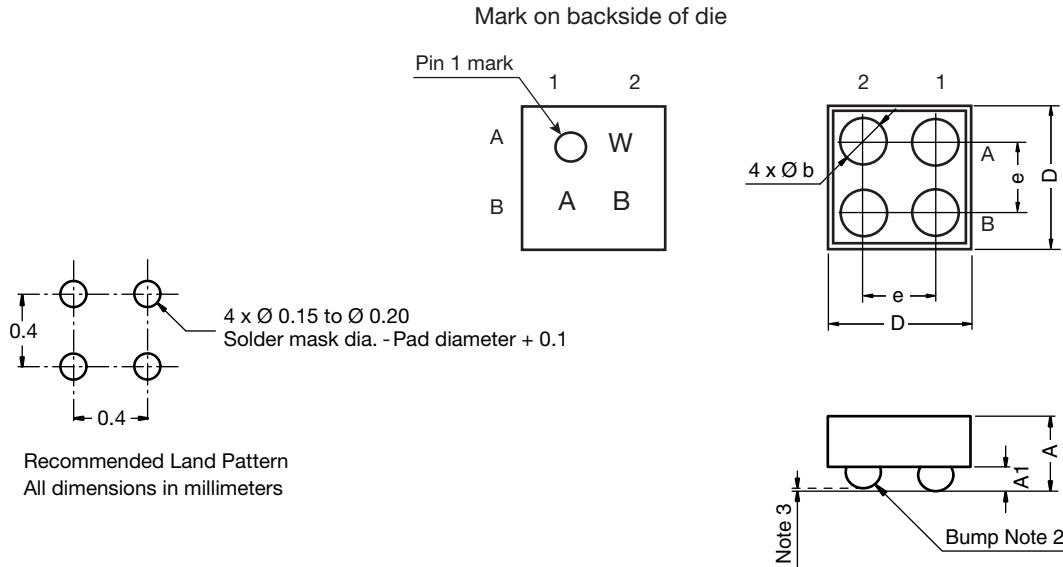


| <b>PRODUCT SUMMARY</b>                       |   |   |
|--|---|---|
| Part number                                  | SiP32454  | SiP32455  |
| Description                                  | 0.8 V to 2.5 V, 28 mΩ, 1.5 ms rise time, output discharge         | 0.8 V to 2.5 V, 28 mΩ, 1.5 ms rise time                           |
| Configuration                                | Single  | Single  |
| Slew rate time (μs)                          | 1000  | 1000  |
| On delay time (μs)                           | 600   | 600   |
| Input voltage min. (V)                       | 0.8   | 0.8   |
| Input voltage max. (V)                       | 2.5   | 2.5   |
| On-resistance at input voltage min. (mΩ)     | 30  | 30  |
| On-resistance at input voltage max. (mΩ)     | 28  | 28  |
| Quiescent current at input voltage min. (μA) | 4   | 4   |
| Quiescent current at input voltage max. (μA) | 32  | 32  |
| Output discharge (yes / no)                  | Yes   | No  |
| Reverse blocking (yes / no)                  | Yes   | Yes   |
| Continuous current (A)                       | 1.2   | 1.2   |
| Package type                                 | WCSP4   | WCSP4   |
| Package size (W, L, H) (mm)                  | 0.8 x 0.8 x 0.5   | 0.8 x 0.8 x 0.5   |
| Status code                                  | 2   | 2   |
| Product type                                 | Slew rate   | Slew rate   |
| Applications                                 | Computers, consumer, industrial, healthcare, networking, portable | Computers, consumer, industrial, healthcare, networking, portable |

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## WCSP4: 4 Bumps

(2 x 2, 0.4 mm pitch, 208 μm bump height, 0.8 mm x 0.8 mm die size)



DWG-No: 6004

### Notes

- (1) Laser mark on the backside surface of die
- (2) Bumps are SAC396
- (3) 0.05 max. coplanarity

| DIM. | MILLIMETERS <sup>a</sup> |       |       | INCHES |        |        |
|------|--------------------------|-------|-------|--------|--------|--------|
|      | MIN.                     | NOM.  | MAX.  | MIN.   | NOM.   | MAX.   |
| A    | 0.515                    | 0.530 | 0.545 | 0.0203 | 0.0209 | 0.0215 |
| A1   | 0.208                    |       |       | 0.0082 |        |        |
| b    | 0.250                    | 0.260 | 0.270 | 0.0098 | 0.0102 | 0.0106 |
| e    | 0.400                    |       |       | 0.0157 |        |        |
| D    | 0.720                    | 0.760 | 0.800 | 0.0283 | 0.0299 | 0.0315 |

### Note

- a. Use millimeters as the primary measurement



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